

CGHV96050F2

50 W, 7.9 - 9.6 GHz, 50-ohm, Input/Output Matched GaN HEMT

Description

The CGHV96050F2 is a gallium nitride (GaN) High Electron Mobility Transistor (HEMT) on Silicon Carbide (SiC) substrates. This GaN Internally Matched (IM) FET offers excellent power added efficiency in comparison to other technologies. GaN has superior properties compared to silicon or gallium arsenide, including higher breakdown voltage, higher saturated electron drift velocity and higher thermal conductivity. GaN HEMTs also offer greater power density and wider bandwidths compared to GaAs transistors. This IM FET is available in a metal/ ceramic flanged package for optimal electrical and thermal performance.



Package Type: 440217

Typical Performance Over 8.4 - 9.6 GHz ($T_c = 25^{\circ}C$)

Parameter	8.4 GHz	8.8 GHz	9.0 GHz	9.2 GHz	9.4 GHz	9.6 GHz	Units
Linear Gain	13.8	12.8	12.3	12.3	12.2	11.8	dB
Output Power	85	77	81	82	75	75	W
Power Gain	10.4	9.9	10.1	10.1	8.8	9.8	dB
Power Added Efficiency	57	54	52	54	48	45	%

Note: Measured in CGHV96050F2-AMP (838179) under 100µs pulse width, 10% duty, P_{IN} 39.0 dBm (7.9 W)

Features

- 8.4 9.6 GHz Operation
- 80 W Pout typical
- 10 dB Power Gain
- 55% Typical PAE
- 50 Ohm Internally Matched
- <0.1 dB Power Droop

Applications

- Marine Radar
- Weather Monitoring
- Air Traffic Control
- Maritime Vessel Traffic Control
- Port Security



Large Signal Models Available for ADS and MWO

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Absolute Maximum Ratings (not simultaneous)

Parameter	Symbol	Rating	Units	Conditions
Drain-source Voltage	V _{DSS}	120	v	25%
Gate-source Voltage	V _{GS}	-10, +2	V	25°C
Power Dissipation	P _{DISS}	57.6 / 86.4	W	(CW / Pulse)
Storage Temperature	T _{STG}	-65, +150	°C	
Operating Junction Temperature	T,	225		
Maximum Drain Current	I _{DMAX}	6	A	
Maximum Forward Gate Current	I _{GMAX}	14.4	mA	25°C
Soldering Temperature ¹	Ts	245	°C	
Screw Torque	τ	40	in-oz	
Thermal Resistance, Junction to Case	P	1.40	00/101	Pulse Width = 100µs, Duty Cycle = 10%, P _{DISS} = 86.4 W
Thermal Resistance, Junction to Case	- R _{θJC}	2.12	°C/W	CW, 85°C, P _{DISS} = 57.6 W
Case Operating Temperature ³	T _c	-40, +125	°C	

Notes:

¹ Current limit for long term, reliable operation

² Refer to the Application Note on soldering

³ See also, the Power Dissipation De-rating Curve on Page 9

Electrical Characteristics (Frequency = 9.6 GHz unless otherwise stated; $T_c = 25^{\circ}C$)

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions	
DC Characteristics ¹							
Gate Threshold Voltage	V _{GS(th)}	-3.8	2.0	-2.3	N	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 14.4 \text{ mA}$	
Gate Quiescent Voltage	V _{GS(Q)}	_	-3.0	_	V	V _{DS} = 40 V, I _D = 500 mA	
Saturated Drain Current ²	I _{DS}	11.5	13.0	-	А	$V_{DS} = 6.0 \text{ V}, V_{GS} = 2.0 \text{ V}$	
Drain-Source Breakdown Voltage	V _{BR}	100	_	_	V	$V_{GS} = -8 V$, $I_{D} = 14.4 mA$	
RF Characteristics ³							
Small Signal Gain	S21	10.0	11.8	_		V_{DD} = 40 V, I_{DQ} = 500 mA, P_{IN} = -20 dBm	
Input Return Loss	S11	_	-5.2	-2.1	dB	$V_{DD} = 40 \text{ V}, I_{DQ} = 500 \text{ mA}, P_{IN} = -20 \text{ dBm},$ f = 8.4 - 9.6 GHz	
Output Return Loss	S22	-	-12.3	-9.0		$V_{DD} = 40 \text{ V}, I_{DQ} = 500 \text{ mA}, P_{IN} = -20 \text{ dBm}$	
Power Output ^{3, 4}	Ρουτ	47	70	_	W	- V _{DD} = 40 V, I _{DQ} = 500 mA, P _{IN} = 39 dBm	
Power Added Efficiency ^{3, 4}	PAE	32	45	_	%		
Output Mismatch Stress	VSWR	_	_	5:1	Ψ	No damage at all phase angles, $V_{DD} = 40 \text{ V}, I_{DQ} = 500 \text{ mA}$	

Notes:

¹ Measured on wafer prior to packaging.

² Scaled from PCM data

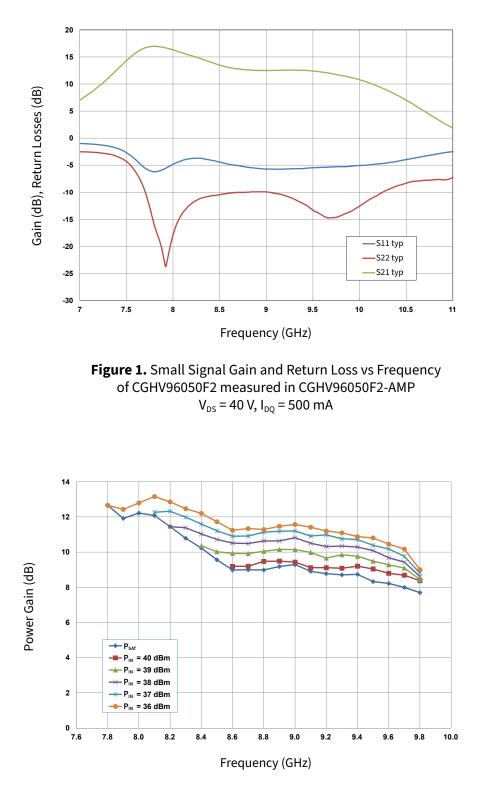
 $^{\scriptscriptstyle 3}$ Measured in CGHV96050F2-AMP (AD-09115) under 100 μs pulse width, 10% duty

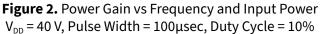
⁴ Fixture loss de-embedded using the following offsets. At 9.6 GHz, input and output = 0.50 dB

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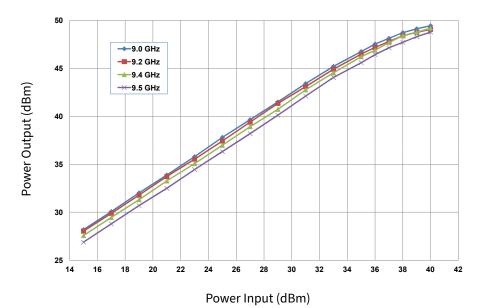
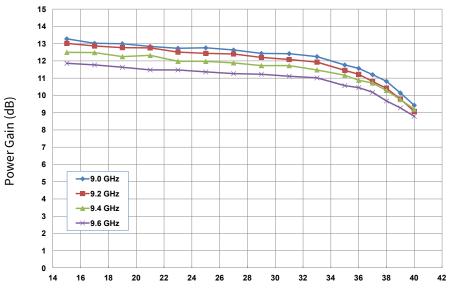
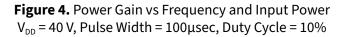


Figure 3. Output Power vs Input Power $V_{DD} = 40 \text{ V}$, Pulse Width = 100 μ sec, Duty Cycle = 10%

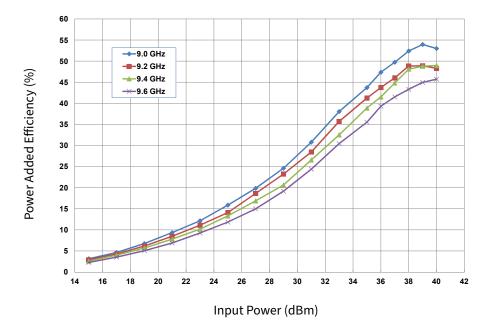


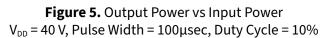
Input Power (dBm)

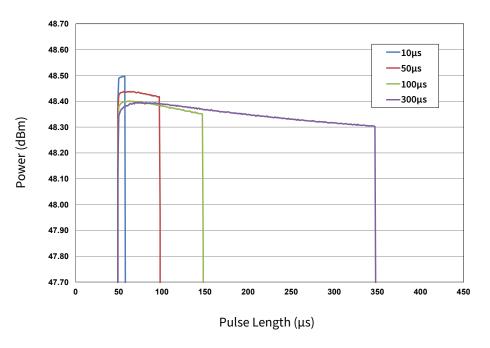


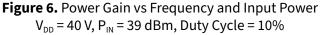
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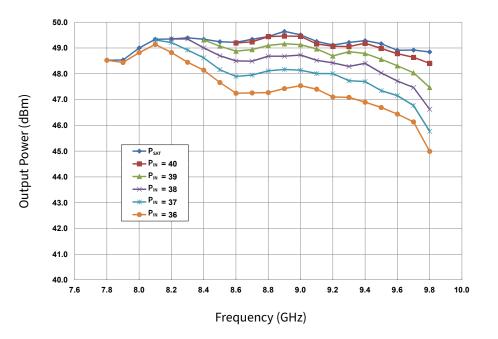
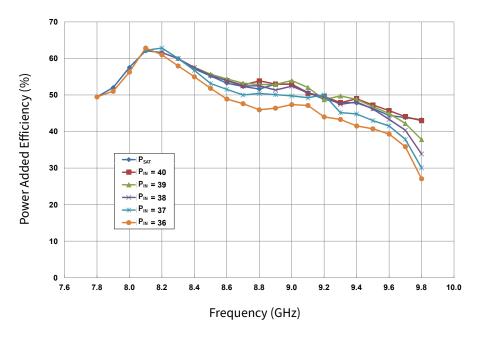
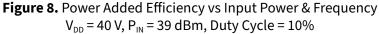


Figure 7. Output Power vs Input Power & Frequency V_{DD} = 40 V, Pulse Width = 100µsec, Duty Cycle = 10%





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CGHV96050F2-AMP Demonstration Amplifier Circuit Bill of Materials

Designator	Description	Qty
R1	RES, 47 OHM, +/- 1%, 1/16W, 0603	1
C1	CAP, 0.9pF, +/- 0.05pF, 200V, 0402	1
C11	CAP, 1.6pF, +/- 0.1pF, 200V, 0402	1
C2, C12	CAP, 1.0pF, +/- 0.1pF, 200V, 0402	2
C3, C13	CAP, 10.0pF, +/-5%, 250V, 0603,	2
C4, C14	CAP, 470pF, 5%, 100V, 0603, X	2
C5, C15	CAP, 33000pF, 0805, 100V, X7R	2
C6	CAP 10µF 16V TANTALUM	1
C18	CAP, 470µF, 20%, 80V, ELECT, SMD Size K	1
J1, J2	CONN, N, FEM, W/.500 SMA FLNG	2
J3	HEADER RT>PLZ .1CEN LK 9POS	1
J4	CONNECTOR; SMB, Straight, JACK, SMD	1
W1	CABLE, 18 AWG, 4.2"	1
	PCB, RF35, 2.5 X 3.0 X (0.020/0.250)	1
	TRANSISTOR, CGHV96050F2	1
	#2 SPLIT LOCKWASHER SS	4
	2-56 SOC HD SCREW 1/4 SS	4

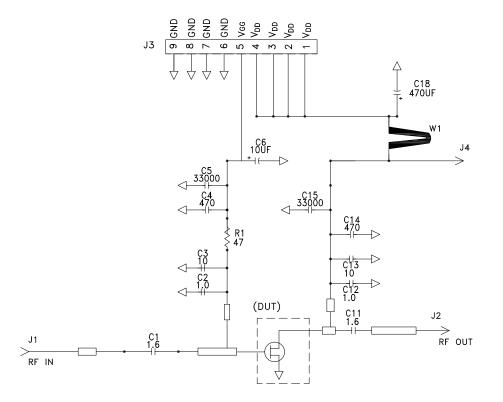
CGHV96050F2-AMP Demonstration Amplifier Circuit



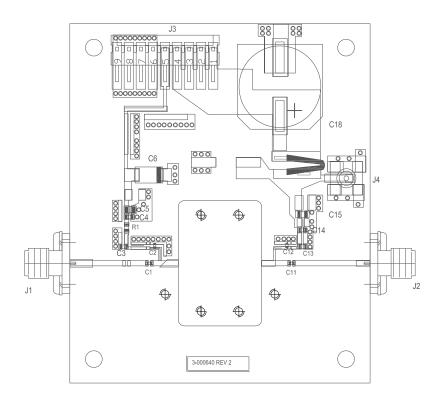
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CGHV96050F2-AMP Demonstration Amplifier Circuit Schematic



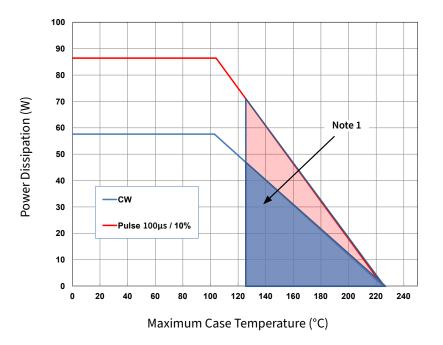
CGHV96050F2-AMP Demonstration Amplifier Circuit Outline



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CGHV96050F2 Power Dissipation De-rating Curve



Note: ¹Area exceeds Maximum Case Temperature (See Page 2)

Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Class	Classification Level	Test Methodology
Human Body Model	НВМ	TBD	ANSI/ESDA/JEDEC JS-001 Table 3	JEDEC JESD22 A114-D
Charge Device Model	CDM	TBD	ANSI/ESDA/JEDEC JS-002 Table 3	JEDEC JESD22 C101-C

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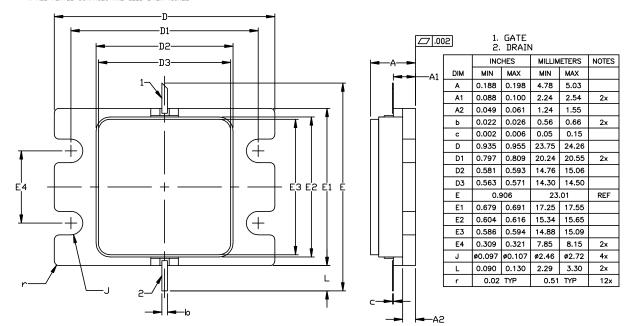
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Product Dimensions CGHV96050F2 (Package Type – 440217)

NOTES: (UNLESS OTHERWISE SPECIFIED)

- 1. INTERPRET DRAWING IN ACCORDANCE WITH ANSI Y14.5M-2009
- 2. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF .020 BEYOND EDGE OF LID
- 3. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF .008 IN ANY DIRECTION
- 4. ALL PLATED SURFACES ARE GOLD DVER NICKEL





Part Number System

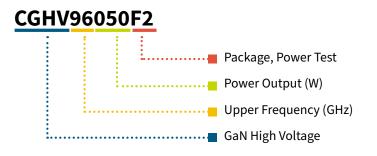


Table 1.

Parameter	Value	Units
Upper Frequency ¹	9.6	GHz
Power Output	50	W
Package	Flange	_

Note:

¹ Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Table 2.

Character Code	Code Value	
A	0	
В	1	
С	2	
D	3	
E	4	
F	5	
G	6	
Н	7	
J	8	
К	9	
Examples	1A = 10.0 GHz 2H = 27.0 GHz	

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Product Ordering Information

Order Number	Description	Unit of Measure	Image
CGHV96050F2	GaN HEMT	Each	Congregations Cractical Congregations
CGHV96050F2-AMP	Test board with GaN HEMT Installed	Each	



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